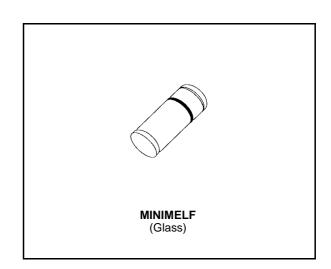


SMALL SIGNAL SCHOTTKY DIODES



DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage and fast switching.

These devices have integrated protection against excessive voltage such as electrostatic discharges.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	TMMBAT47	TMMBAT48	Unit	
V_{RRM}	Repetitive Peak Reverse Voltage	20	40	V	
I _F	Forward Continuous Current	T _I = 25 °C	35	50	mA
I _{FRM}	Repetitive Peak Fordward Current	$\begin{array}{l} t_p \leq 1s \\ \delta \leq 0.5 \end{array}$		Α	
I _{FSM}	Surge non Repetitive Forward Current	t _p = 10ms	7	Α	
		t _p = 1s	1.5		
P _{tot}	Power Dissipation	T _I = 25 °C	330		mW
T _{stg} T _j	Storage and Junction Temperature Range	- 65 to 150 - 65 to 125		ဝိ ဝိ	
T _L	Maximum Temperature for Soldering during 15	260		°C	

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
R _{th(j-l)}	Junction-leads	300	°C/W

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol		Test Conditions	S	Min.	Тур.	Max.	Unit
V_{BR}	T _j = 25°C	$I_R = 10\mu A$	TMMBAT47	20			V
	T _j = 25°C	$I_R = 25\mu A$	TMMBAT48	40			
V _F *	T _j = 25°C	$I_F = 0.1 \text{mA}$	All Types			0.25	V
	T _j = 25°C	$I_F = 1mA$				0.3	
	T _j = 25°C	$I_F = 10 \text{mA}$				0.4	
	T _j = 25°C	$I_F = 30 \text{mA}$	TMMBAT47			0.5	
	T _j = 25°C	$I_F = 150 \text{mA}$				0.8	
	T _j = 25°C	$I_F = 300 \text{mA}$				1	
	T _j = 25°C	$I_F = 50 \text{mA}$	TMMBAT48			0.5	
	T _j = 25°C	$I_F = 200 \text{mA}$				0.75	
	T _j = 25°C	$I_F = 500 \text{mA}$				0.9	
I _R *	T _j = 25°C	V _R = 1.5V	All Types			1	μΑ
	T _j = 60°C					10	
	T _j = 25°C	V _R = 10V	TMMBAT47			4	
	$T_j = 60^{\circ}C$					20	
	T _j = 25°C	V _R = 20V				10	
	$T_j = 60^{\circ}C$					30	
	T _j = 25°C	V _R = 10V	TMMBAT48			2	
	T _j = 60°C					15	
	T _j = 25°C	V _R = 20V				5	
	T _j = 60°C					25	
	T _j = 25°C	V _R = 40V				25	
	T _i = 60°C					50	

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Тур.	Max.	Unit
С	T _j = 25°C	$V_R = 0V$	f = 1MHz		20		pF
	T _j = 25°C	$V_R = 1V$			12		
t _{rr}	T _j = 25°C	$I_F = 10 \text{mA}$ $V_R = 1 \text{V}$ $i_{rr} =$	1mA $R_L = 100\Omega$		10		ns

* Pulse test: $t_p \le 300 \mu s$ $\delta < 2\%$.

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Figure 1. Forward current versus forward voltage at different temperatures (typical values).

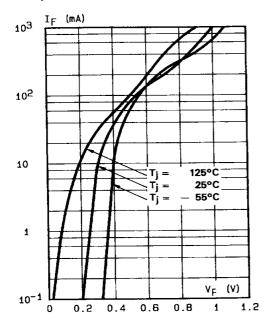


Figure 2. Forward current versus forward voltage (typical values).

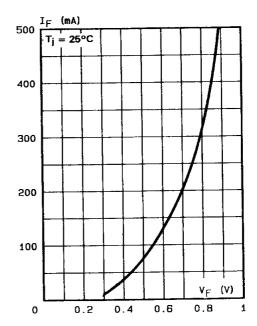


Figure 3. Reverse current versus junction temperature.

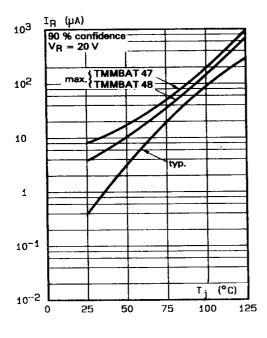
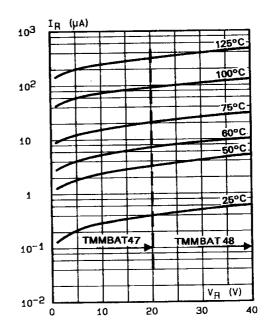


Figure 4. Reverse current versus continuous reverse voltage (typical values).



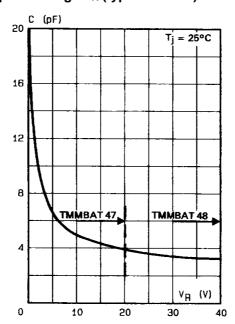
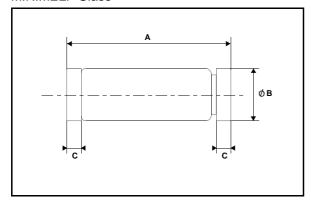


Figure 5. Capacitance C versus reverse applied voltage $V_{\mbox{\scriptsize R}}$ (typical values).

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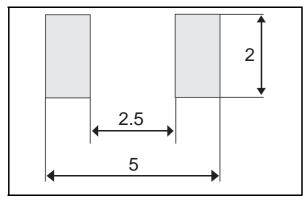
PACKAGE MECHANICAL DATA

MINIMELF Glass



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	3.30	3.40	3.6	0.130	0.134	0.142	
В	1.59	1.60	1.62	0.063	0.063	0.064	
С	0.40	0.45	0.50	0.016	0.018	0.020	
D		1.50			0.059		

FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end. Weight: 0.05g

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